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Application No. 10/007,754	Prepared by	BSH .	Tracking Number	05974680
Examiner-GAU Flynn-2826	Date	0723-04	Week Date	6-28-04
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				Application Number	10/007,754
INFORM	ATION DISC	CLOSURE		Filing Date	
STATEMENT BY APPLICANT		First Named Inventor	Darrell G. Hill		
OTATEMENT DY 7 T EVER				Group Art Unit	
(use as mar	ny sheets as nec	essary)		Examiner Name	*
Sheet	2	of	2	Attorney Docket Number	SC10776P C01

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	····			
Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				
* *	19	H. Lin et al., "Super-Gain AlGaAs/GaAs Heterojunction Bipolar Transistors Using An Emitter Edge-Thinning Design", American Institute of Physics, appl. Phys. Letter 47(8), 15 October 1985, pages 839-841.				
· · · · · · · · · · · · · · · · · · ·	20	W. Lee et al., "Effect of Emitter-Base Spacing on the current Gain of AlGaAs/GaAs Heterojunction Bipolar Transistors", IEEE Electronic Device Letters, Vol. 10, No. 5, May 1989, pages 200-202.				
	21	Wolf, S., "Silicon Processing for the VLSI Era, Volume 2", Process Integration, Sunset Beach, CA, 1990, pages 486-488.				
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